Diode Semiconductor Device - Page 1 of 1



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	laterial:
Glass	
Overall Len	gth:
Between 0.2	230 inches and 0.300 inches
Terminal Le	ength:
Between 1.0	000 inches and 1.500 inches
Overall Dia	meter:
Between 0.0	085 inches and 0.107 inches
Electrode Ir	nternally-electrically Connected To Case:
Cathode	
Mounting N	lethod:
Terminal	
Features Pr	rovided:
Hermetically	r sealed case
Semicondu	ctor Material:
Silicon	
Voltage Rat	ing In Volts Per Characteristic:
100.0 regu	lator voltage
Current Rat	ing Per Characteristic:
1.00 milliam	peres source cutoff current pascal
Maximum C	Operating Tempurature Per Measurement Point:
175.0 degre	es celsius ambient air
Test Data D	ocument:
81349-mil-s-	19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excl	udes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environment	al and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Ty	vpe And Quantity:
2 uninsulate	d wire lead
Specificatio	on Data:
81349-mil-s-	19500/463 government specification
Shelf Life:	
N/a	
Unit Of Mea	isure:
Demilitariza	ation:
No	
Fiig:	